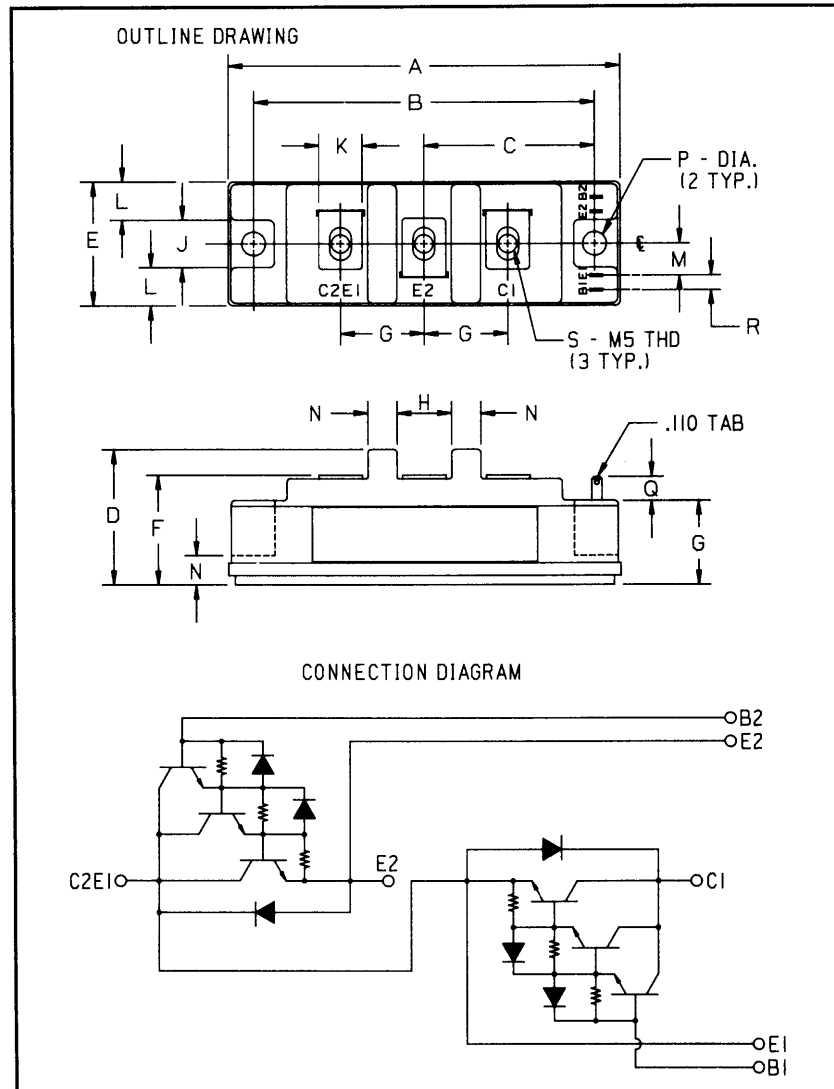


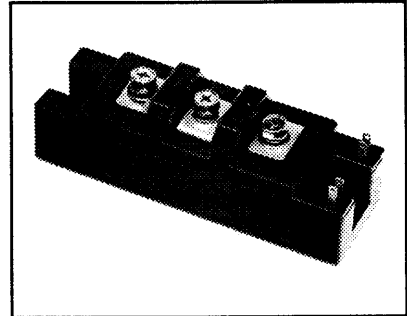
### Dual Darlington Transistor Module 75 Amperes/1200 Volts



Outline Drawing

| Dimensions | Inches        | Millimeters |
|------------|---------------|-------------|
| A          | 4.252 Max.    | 108 Max.    |
| B          | 3.661 ± 0.012 | 93 ± 0.3    |
| C          | 1.831         | 46.5        |
| D          | 1.457         | 37          |
| E          | 1.339 Max.    | 34 Max.     |
| F          | 1.181 Max.    | 30 Max.     |
| G          | 0.906         | 23          |
| H          | 0.591         | 15          |
| J          | 0.512         | 13          |

| Dimensions | Inches     | Millimeters |
|------------|------------|-------------|
| K          | 0.472      | 12          |
| L          | 0.413      | 10.5        |
| M          | 0.344      | 8.75        |
| N          | 0.315      | 8           |
| P          | 0.256 Dia. | 6.5 Dia.    |
| Q          | 0.256 Min. | 6.5 Min.    |
| R          | 0.157      | 4           |
| S          | M5 Metric  | M5          |



#### Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

#### Features:

- ☐ Isolated Mounting
- ☐ Planar Chips
- ☐ Discrete Fast Recovery Feedback Diode
- ☐ High Gain ( $h_{FE}$ )
- ☐ Quick Connect Base-Emitter Signal Terminals
- ☐ Base-Emitter Speed-up Diodes

#### Applications:

- ☐ AC Motor Control
- ☐ DC Motor Control
- ☐ Switching Power Supplies
- ☐ Inverters

#### Ordering Information:

Example: Select the complete ten digit module part number you desire from the table - i.e. KD221275A7 is a 1200 Volt, 75 Ampere Dual Darlington Module with a gain of 75 at rated current (75 Amperes).

| Type | V <sub>CEO(sus)</sub><br>Volts (1000) | Current Rating<br>Amperes (75) |
|------|---------------------------------------|--------------------------------|
| KD22 | 1K                                    | 75                             |



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

**KD221275A7**  
**Dual Darlington Transistor Module**  
 75 Amperes/1200 Volts

**Absolute Maximum Ratings,  $T_J = 25^\circ\text{C}$  unless otherwise specified**

| Ratings                                                     | Symbol         | KD221275A7 | Units            |
|-------------------------------------------------------------|----------------|------------|------------------|
| Junction Temperature                                        | $T_J$          | -40 to 150 | $^\circ\text{C}$ |
| Storage Temperature                                         | $T_{stg}$      | -40 to 125 | $^\circ\text{C}$ |
| Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$ | $V_{CEV(sus)}$ | 1200       | Volts            |
| Collector-Base Voltage                                      | $V_{CBO}$      | 1200       | Volts            |
| Emitter-Base Voltage                                        | $V_{EBO}$      | 7          | Volts            |
| Collector-Emitter Voltage, $V_{BE} = -2\text{V}$            | $V_{CEV}$      | 1200       | Volts            |
| Continuous Collector Current                                | $I_C$          | 75         | Amperes          |
| Diode Forward Current                                       | $I_{FM}$       | 75         | Amperes          |
| Continuous Base Current                                     | $I_B$          | 4          | Amperes          |
| Diode Surge Current                                         | $I_{FSM}$      | 750        | Amperes          |
| Power Dissipation (Each Transistor)                         | $P_t$          | 500        | Watts            |
| Max. Mounting Torque M5 Terminal Screws                     | —              | 17         | in.-lb.          |
| Max. Mounting Torque M6 Mounting Screws                     | —              | 26         | in.-lb.          |
| Module Weight (Typical)                                     | —              | 250        | Grams            |
| V Isolation                                                 | $V_{RMS}$      | 2500       | Volts            |

**Electrical Characteristics,  $T_J = 25^\circ\text{C}$  unless otherwise specified**

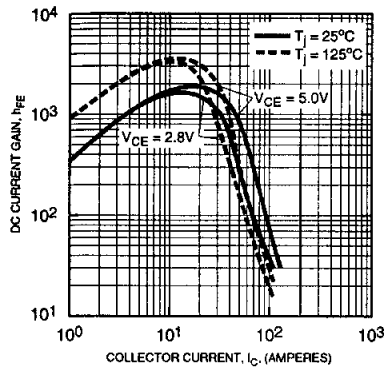
| Characteristics                      | Symbol        | Test Conditions                                                       | Min. | Typ. | Max. | Units         |
|--------------------------------------|---------------|-----------------------------------------------------------------------|------|------|------|---------------|
| Collector Cutoff Current             | $I_{CEV}$     | $V_{CE} = 1200\text{V}, V_{BE} = -2\text{V}$                          | —    | —    | 1    | mA            |
|                                      |               | $V_{CE} = 1200\text{V}, V_{BE} = -2\text{V}, T_C = 125^\circ\text{C}$ | —    | —    | 10   | mA            |
| Emitter Cutoff Current               | $I_{EBO}$     | $V_{EB} = 7\text{V}$                                                  | —    | —    | 200  | mA            |
| DC Current Gain                      | $h_{FE}$      | $I_C = 75\text{A}, V_{CE} = 5\text{V}$                                | 75   | —    | —    | —             |
| Diode Forward Voltage                | $V_{FM}$      | $I_{FM} = 75\text{A}$                                                 | —    | —    | 1.8  | Volts         |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C = 75\text{A}, I_B = 1.5\text{A}$                                 | —    | —    | 3.0  | Volts         |
| Base-Emitter Saturation Voltage      | $V_{BE(sat)}$ | $I_C = 75\text{A}, I_B = 1.5\text{A}$                                 | —    | —    | 3.5  | Volts         |
| Resistive                            | Turn-on       | $V_{CC} = 600\text{V}$                                                | —    | —    | 2.5  | $\mu\text{s}$ |
| Load                                 | Storage Time  |                                                                       |      |      |      |               |
|                                      |               | $I_C = 75\text{A}$                                                    | —    | —    | 15   | $\mu\text{s}$ |
| Switch Times                         | Fall Time     | $I_{B1} = 1.5\text{A}, I_{B2} = -1.5\text{A}$                         | —    | —    | 3.0  | $\mu\text{s}$ |

**Thermal and Mechanical Characteristics,  $T_J = 25^\circ\text{C}$  unless otherwise specified**

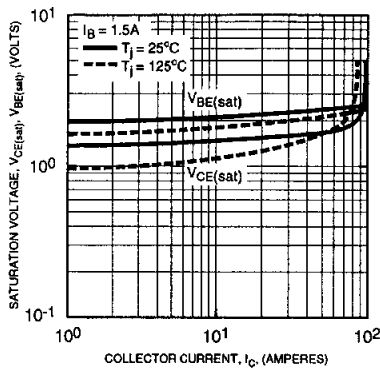
| Characteristics                      | Symbol            | Test Conditions | Min. | Typ. | Max. | Units              |
|--------------------------------------|-------------------|-----------------|------|------|------|--------------------|
| Thermal Resistance, Case-to-Sink     | $R_{\theta(c-s)}$ | Per 1/2 Module  | —    | —    | 0.13 | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction-to-Case | $R_{\theta(j-c)}$ | Transistor Part | —    | —    | 0.25 | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction-to-Case | $R_{\theta(j-c)}$ | Diode Part      | —    | —    | 1.2  | $^\circ\text{C/W}$ |

**KD221275A7**  
**Dual Darlington Transistor Module**  
 75 Amperes/1200 Volts

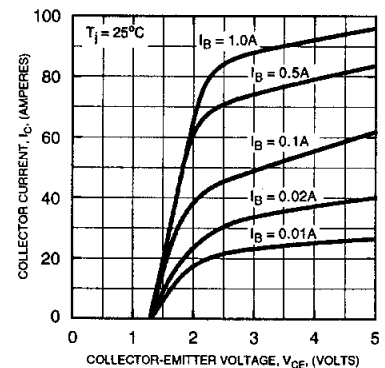
**DC CURRENT GAIN (TYPICAL)**



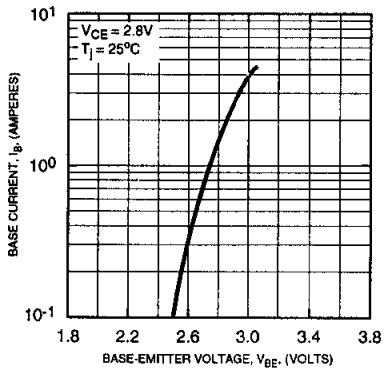
**SATURATION VOLTAGE (TYPICAL)**



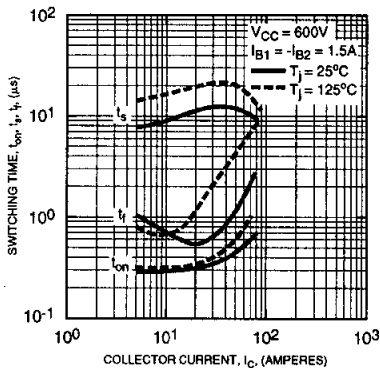
**COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)**



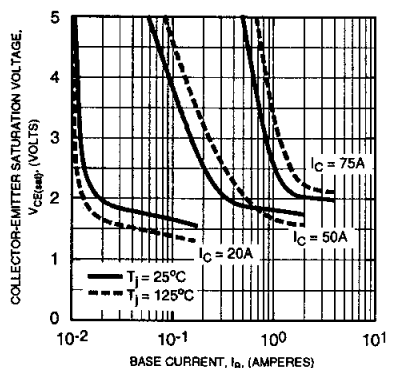
**COMMON EMITTER INPUT CHARACTERISTICS (TYPICAL)**



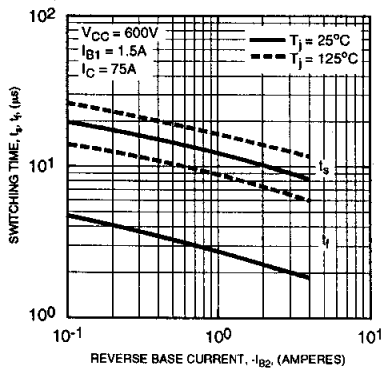
**SWITCHING CHARACTERISTICS (TYPICAL)**



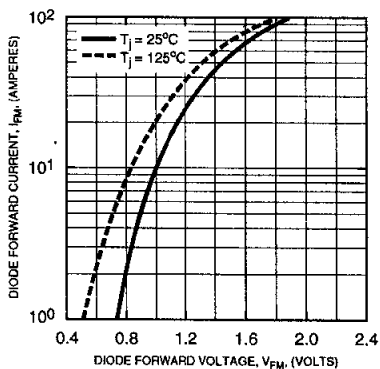
**COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)**



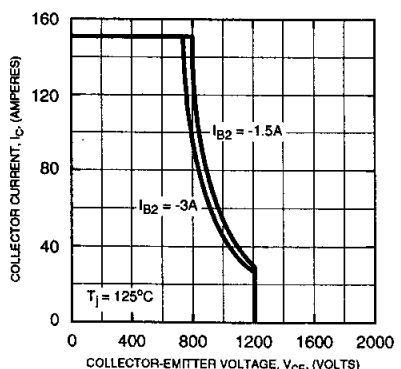
**SWITCHING TIME VS. BASE CURRENT (TYPICAL)**



**DIODE CHARACTERISTICS (TYPICAL)**



**REVERSE BIAS SAFE OPERATING AREA (RBSOA)**



**KD221275A7**  
**Dual Darlington Transistor Module**  
 75 Amperes/1200 Volts

